

TSM10P06

60V P-Channel MOSFET



TO-252 (DPAK)



Pin Definition:

- 1. Gate
- 2. Drain
- 3. Source

PRODUCT SUMMARY

V _{DS} (V)	R _{DSON} (mΩ)	I _D (A)	
00	170 @ V _{GS} = -10V	-5	
-60	220 @ V _{GS} = -4.5V	-2	

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

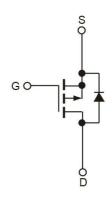
- Load Switch
- PA Switch

Ordering Information

Part No.	Package	Packing
TSM10P06CP ROG	TO-252	2.5Kpcs / 13" Reel

Note: "G" denote for Halogen Free Product

Block Diagram



P-Channel MOSFET

Absolute Maximum Rating (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current	I _D	-10	А
Pulsed Drain Current	I _{DM}	-20	А
Continuous Source Current (Diode Conduction) ^{a,b}	Is	-10	А
Single Pulse Avalanche Energy (Note 2)	E _{AS}	5	mJ
Avalanche Current	I _{AS}	-10	А
Total Power Dissipation @ T _C =25C	P _{DTOT}	37	W
Operating Junction Temperature	T _J	+150	°C
Operating Junction and Storage Temperature Range	T _J , T _{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	$R\Theta_{JC}$	4	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	$R\Theta_{JA}$	70	°C/W

Notes:

- a. Pulse width limited by the Maximum junction temperature
- b. Surface Mounted on FR4 Board, t ≤ 10 sec.

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Electrical Specifications (Ta = 25°C unless otherwise noted)

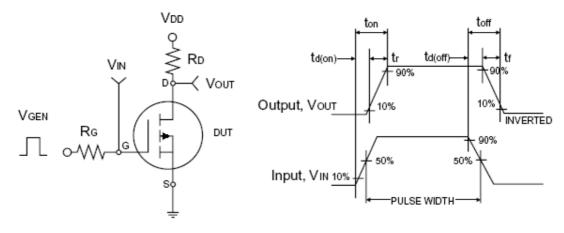
Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250uA$	BV _{DSS}	-60			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	-1			V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -60V, V_{GS} = 0V$	I _{DSS}			-1	μA
On-State Drain Current ^a	$V_{DS} = -5V, V_{GS} = -10V$	I _{D(ON)}	-10			Α
Drain-Source On-State Resistance	$V_{GS} = -10V, I_D = -5A$			130	170	mΩ
Dialii-Source Ori-State Resistance	$V_{GS} = -5V, I_D = -2A$	$R_{DS(ON)}$		170	220	
Forward Transconductance	$V_{DS} = -15V, I_{D} = -3.5A$	g _{fs}	-	6		S
Diode Forward Voltage	$I_S = -2.5A, V_{GS} = 0V$	V_{SD}		-1.25	-1.5	V
Dynamic						
Total Gate Charge	$V_{DS} = -15V, I_{D} = -3.5A,$ $V_{GS} = -10V$	Q_g		6		
Gate-Source Charge		Q_gs		1.7		nC
Gate-Drain Charge		Q_{gd}		1.5		
Input Capacitance	$V_{DS} = -30V, V_{GS} = 0V,$ $f = 1.0MHz$	C_{iss}		540		
Output Capacitance		C _{oss}	-	60		pF
Reverse Transfer Capacitance	1 = 1.0IVINZ	C _{rss}	-	30		
Switching						
Turn-On Delay Time	$V_{DD} = -15V, R_{L} = 15\Omega,$ $I_{D} = -1A, V_{GEN} = -10V,$	t _{d(on)}		7		
Turn-On Rise Time		t _r		9		20
Turn-Off Delay Time		t _{d(off)}		19		nS
Turn-Off Fall Time	$R_G = 6\Omega$	t _f		4		

Notes 1: Pulse test: PW ≤300µS, duty cycle ≤2%

Notes 2: L=0.1mH,

Notes 3: For DESIGN AID ONLY, not subject to production testing.

Notes 4: Switching time is essentially independent of operating temperature.



Switching Test Circuit

Switchin Waveforms

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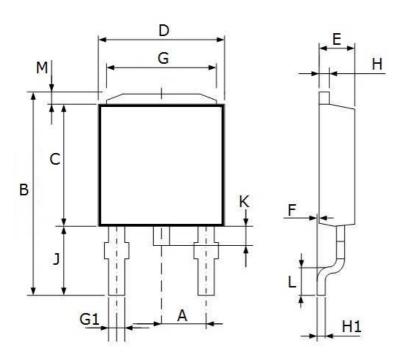


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TO-252 Mechanical Drawing



TO-252 DIMENSION					
5.1.4	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	2.30	BSC	0.090	BSC	
В	10.20	10.80	0.402	0.425	
С	5.30	5.70	0.209	0.224	
D	6.30	6.70	0.248	0.264	
Е	2.10	2.50	0.083	0.098	
F	0.00	0.20	0.000	0.008	
G	4.80	5.20	0.189	0.205	
G1	0.40	0.80	0.016	0.031	
Н	0.40	0.60	0.016	0.024	
H1	0.35	0.65	0.014	0.026	
J	3.35	3.65	0.132	0.144	
K	0.50	1.10	0.020	0.043	
L	0.90	1.50	0.035	0.059	
М	1.30	1.70	0.051	0.067	

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